NUP4060AXV6

ESD Protection Diode Array, 4-Line

This 4-line surge protection array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as cell phones, portables, computers, printers and other applications. This device features a common cathode design which protects four independent lines in a single SOT-563 package.

Features

- Protects up to 4 Lines in a Single SOT-563 Package
- ESD Rating: IEC61000-4-2: Level 4 Contact (8 kV), Air (15 kV)
- V_{CC} Pin = 16 V Protection
 D1, D2, and D3 Pins = 6.8 V Protection
- Low Capacitance (< 7 pF @ 3 V) for D₁, D₂, and D₃
- This is a Pb-Free Device

Applications

- Hand Held Portable Applications
- USB Interface
- Notebooks, Desktops, Servers
- SIM Card Protection

MAXIMUM RATINGS (T_J = 25°C, unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation V _{CC} Diode 8x20 μsec double exponential waveform,	200	W
	(Note 1) D ₁ , D ₂ , and D ₃	20	W
TJ	Operating Junction Temperature Range	-40 to 125	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
TL	Lead Solder Temperature – Maximum (10 seconds)	260	°C
ESD	IEC 61000-4-2 Air IEC 61000-4-2 Contact	15000 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Nonrepetitive current pulse per Figure 1.

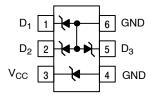


ON Semiconductor®

www.onsemi.com

SOT-563 4-LINE SURGE PROTECTION

PIN ASSIGNMENT



MARKING DIAGRAM



SOT-563 CASE 463A STYLE 6



MT = Specific Device Code

M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NUP4060AXV6T1G	SOT-563 (Pb-Free)	4000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NUP4060AXV6

ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Reverse Working Voltage (D ₁ , D ₂ , and D ₃)	(Note 2)	V_{RWM}	-	-	5.0	V
Breakdown Voltage (D ₁ , D ₂ , and D ₃)	I _T = 1 mA, (Note 3)	V_{BR}	6.2	6.8	7.2	V
Breakdown Voltage (V _{CC})	I _T = 5 mA, (Note 3)	V _{BR2}	15.3	16	17.1	V
Reverse Leakage Current (D ₁ , D ₂ , and D ₃)	V _{RWM} = 3 V	I _R	-	0.01	0.5	μΑ
Reverse Leakage Current (V _{CC})	V _{BR} = 11 V	I _R	-	-	0.05	μΑ
Capacitance (D ₁ , D ₂ , and D ₃)	V _R = 3 V, f = 1 MHz (Line to GND)	CJ	_	7	10	pF

Surge protection devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
 V_{BR} is measured at pulse test current I_T.

NUP4060AXV6

TYPICAL ELECTRICAL CHARACTERISTICS

(Diode D₁, D₂, and D₃ only)

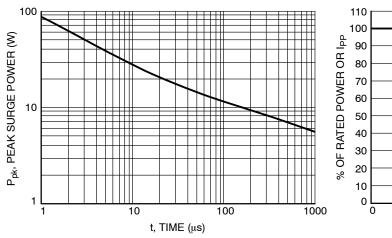
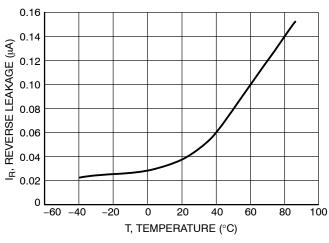


Figure 1. Pulse Width

Figure 2. Power Derating Curve



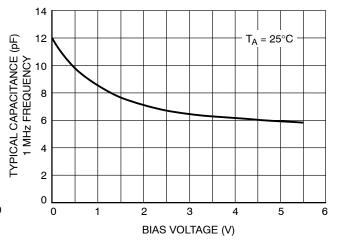
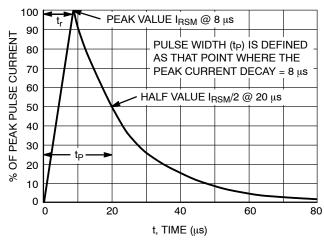


Figure 3. Reverse Leakage versus Temperature

Figure 4. Capacitance



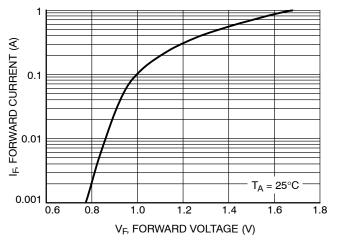


Figure 5. $8 \times 20 \mu s$ Pulse Waveform

Figure 6. Forward Voltage



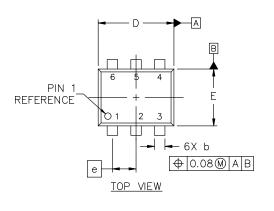


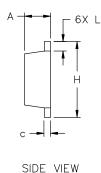
SOT-563-6 1.60x1.20x0.55, 0.50P CASE 463A **ISSUE J**

DATE 15 FEB 2024

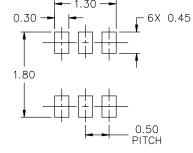
NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.





DIM	MILLIMETERS			
	MIN.	N□M.	MAX.	
А	0.50	0.55	0.60	
b	0.17	0.22	0.27	
\cup	0.08	0.13	0.18	
D	1.50	1.60	1.70	
Ε	1.10	1.20	1.30	
е	0.50 BSC			
I	1.50	1.60	1.70	
L	0.10	0.20	0.30	
D E e	1.50 1.10 1.50	1.60 1.20 0.50 BSC	1.70 1.30	



STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. EMITTER 1	PIN 1. EMITTER 1	PIN 1. CATHODE 1
2. BASE 1	2. EMITTER 2	2. CATHODE 1
3. COLLECTOR 2	3. BASE 2	3. ANODE/ANODE 2
4. EMITTER 2	4. COLLECTOR 2	4. CATHODE 2
5. BASE 2	5. BASE 1	5. CATHODE 2
6. COLLECTOR 1	6. COLLECTOR 1	6. AN□DE/AN□DE 1

STYLE 6: PIN 1. CATHODE 2. ANODE

3. CATHODE

4. CATHODE 5. CATHODE

CATHODE

RECOMMENDED	MOLINITING	FOOTPRINT*
KECOMIMENDED	MOONTING	LOO INKINI.

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE	STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN	STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2
4. CATHUDE	4. SHURCE	4. SHURCE 2
5. AN□DE	5. DRAIN	5. GATE 2
6. CATHUDE	6. DRAIN	6. DRAIN 1

2. BASE 2 3. COLLECTOR 1

EMITTER 1

5. BASE 1

STYLE 11: PIN 1. EMITTER 2

STYLE 5

PIN 1. CATHODE

2. CATHODE

3. ANDDE 4. ANDDE 5. CATHODE

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

M = Month Code = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking

	Timed versions are discontinued except when stamped continued to		PAGE 1 OF 1
DOCUMENT NUMBER:	98AON11126D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
6. ANDDE 1	6. CULLECTUR 2	not follow the deficite Marking.	

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

STYLE 4: PIN 1. COLLECTOR

STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2

5. N/C

4. ANDDE 2

2. COLLECTOR

3. BASE
4. EMITTER
5. COLLECTOR

COLLECTOR

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales